### Industrial Photoelectric Sensors Shock Resistance 50G F.S. 8mm for Precise **Measurements**

#### **Basic Information**

- Place of Origin:
- Brand Name:
- Certification: CE
- Model Number: • Minimum Order Quantity:
- Price: Negotiable
- Packaging Details: Polybag packing
- Delivery Time: 5-8 working days
- Payment Terms: T/T,Western Union,MoneyGram

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Guangdong, China

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KD50-50N

• Supply Ability: 10000 pieces per month

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### **Product Specification**

| Weight:                          | Cable Type: 65g                    |
|----------------------------------|------------------------------------|
| Storage Temperature:             | -20~60°C                           |
| Storage Humidity:                | 35~95%RH(no Condensation Or Icing) |
| • Spot Size (max.) Near Range:   | 0.15x0.15mm                        |
| • Spot Size (max.) Far<br>Range: | 0.15x0.15mm                        |
| Linearity Accuracy:              | ±0.1%F.S.                          |
| Housing Material:                | Housing: PBT, Lens: PMMA           |

- Spot Size (max.) Center 0.1x0.1mm Range:
- Highlight:

Industrial Photoelectric Sensors 8mm, Industrial Photoelectric Sensors Shock Resistance In decated at the standard state





#### **Product Description:**

The Photoelectric Sensors product offers reliable detection capabilities for various applications. With a spot size (max.) far range of 0.15x0.15mm, these sensors deliver precise and accurate results. The IEC/JIS Rating (FDA Rating) of Class 2 (Class II) ensures compliance with industry standards, making them suitable for a wide range of environments. What is a CMOS Laser Displacement Photoelectric Sensor?

A CMOS Laser Displacement Photoelectric Sensor is a high-precision sensor that uses a laser beam and a CMOS image chip to measure the exact distance between the sensor and a target surface without touching it.









| Cable Type               | 2CH                           | KD50-50N  |  |  |
|--------------------------|-------------------------------|---|--|--|
| Output Signal            |                               | Switching output: NPN (-N),   |  |  |
| Detection Rang           | ge                            | 50±10mm   |  |  |
| Full Scale(F.S.          | )                             | 20mm  |  |  |
| Light Source             |                               | Red Laser diode (wavelength 655nm)  |  |  |
| IEC/JIS Rating           | (FDA Rating)                  | Class 2(Class )   |  |  |
| Sampling Perio           | bd                            | 500(250mm:750)/1000/1500/2000µs   |  |  |
|                          | High-speed<br>Mode            | max.5ms: sampling average x 1 (1ms) + sensitivity switch time (max.4ms)           |  |  |
| Response<br>Time         | Standard<br>Mode              | max.12.5ms: sample average x 16 (8.5ms) + sensitivity switch time (max.4ms)       |  |  |
|                          | High-<br>resolution<br>Mode   | max.36.5ms: sampling average x 64 (32.5ms) + sensitivity<br>switch time (max.4ms) |  |  |
|                          | Sensitivity<br>Switch<br>Time | 4ms max.  |  |  |
| Operating Temp./Humidity |                               | -10~45° C/35~85%RH(no condensation or icing)                                      |  |  |
| Shock Resistance         |                               | 50G(500m/s <sup>2</sup> )   |  |  |
| Housing Material         |                               | Housing: PBT Lens: PMMA   |  |  |
| Vibration Resistance     |                               | 10~55Hz, double amplitude 1.5mm,X,Y,Z directions, 2 hour for each                 |  |  |

## **KD50 Series**

## **CMOS Laser Displacement Sensor**

· Built-in analog output and 2 digital outputs, operable without a controller connection.

- High-precision photosensitivity calibration auto-optimizes received light intensity.
- Digital subpixel processing technology delivers over twice the linear accuracy of
- conventional displacement sensors.

 Remote input (MF line) enables functions including: laser emission off, external teach-in, output hold, and single-pulse input.

#### **Technicial Parameters**

#### Diffuse Reflection

|                     |          | 2CH                                   | KD50-30N(P)  | KD50-50N(P)  | KD50-85N(P)                | KD50-120N(P)            | KD50-250N(P)                           |  |
|---------------------|----------|---------------------------------------|--|--|----------------------------|-------------------------|--|--|
| Cable 2             | 2CH+A    | Analog Current                        | KD50-30N(P)I   | KD50-50N(P)I   | KD50-85N(P)I               | KD50-120N(P)I           | KD50-250N(P)I                          |  |
| Туре                | 2CH+/    | Analog Voltage                        | KD50-30N(P)U   | KD50-50N(P)U   | KDS0-8SN(P)U               | KD50-120N(P)U           | KD50-250N(P)U                          |  |
|                     | 1        | CH+RS422                              | KD50-30N(P)/R2   | KD50-50N(P)/R2   | KD50-85N(P)/R2             | KD50-120N(P)/R2         | KD50-250N(P)/R2                        |  |
|                     |          | 2CH                                   | KD50-30N(P)-A8   | KD50-50N(P)-A8   | KD50-85N(P)-A8             | KD50-120N(P)-A8         | KD50-250N(P)-A8                        |  |
| Plug-in             | 2CH+#    | Analog Current                        | KD50-30N(P)I-A8  | KD50-50N(P)I-A8  | KD50-85N(P)I-A8            | KD50-120N(P)I-A8        | KD50-250N(P)I-A8                       |  |
| Туре                | 2CH+/    | Analog Voltage                        | KD50-30N(P)U-A8  | KD50-50N(P)U-AB  | KD50-85N(P)U-A8            | KD50-120N(P)U-A8        | KD50-250N(P)U-A8                       |  |
|                     | 1        | CH+RS422                              | KD50-30N(P)/R2-A8  | KD50-50N(P)/R2-A8  | KD50-85N(P)/R2-A8          | KD50-120N(P)/R2-AB      | KD50-250N(P)/R2-A                      |  |
|                     | Dutput   | Signal                                | Switching output: NF   | N (-N), PNP (-P); Analog                                     | output: current 4-20mA     | , voltage 0-10V; Commun | nication output: RS-422                |  |
| De                  | etection | n Range                               | 30±4mm   | 50±10mm  | 85±20mm                    | 120±60mm                | 250±150mm                              |  |
| Fu                  | ll Scale | (F.S.)                                | 8mm  | 20mm   | 40mm                       | 120mm                   | 300mm                                  |  |
|                     | Light S  | ource                                 |  | Red La   | ser diode (wavelengt       | h 655nm)                |  |  |
| IEC/JIS R           | ating    | (FDA Rating)                          |  |  | Class 2(Class II )         |                         |  |  |
| Sa                  | mpling   | g Period                              | 500 (250)  | nm: 750) /1000/150   | 00/2000µs ;factory se      | tting: 500µs (250mr     | m: 750µs)                              |  |
|                     |          | Near Range                            | 0.15x0.15mm  | 0.6x1.2mm  | 0.9x1.5mm                  | 1.2x1.8mm               | 1.5x2.5mm                              |  |
| Spot S              | ize      | Center Range                          | 0.1x0.1mm  | 0.5x1.0mm  | 0.75x1.25mm                | 1.0x1.5mm               | 1.75x3.5mm                             |  |
| Inax                | -/       | Far Range                             | 0.15x0.15mm  | 0.4x0.9mm  | 0.6x1.0mm                  | 0.5x0.8mm               | 2.0x4.5mm                              |  |
| Lin                 | earity A | Accuracy                              |  |  | ±0.1%F.S.                  |                         |  |  |
| -                   |          | High-speed Mode                       | 4µm  | 8µm  | 15µm                       | 45µm                    | 100µm                                  |  |
| Repeata             | bility   | Other Mode                            | 2μm  | 5µm  | 10µm                       | 30µm                    | 75µm                                   |  |
| Te                  | mperat   | ure Drift                             |  |  | ±0.08%F.S./° C             |                         |  |  |
|                     |          | High-speed Mode                       | max.5ms: sampling average x 1 (1ms) + sensitivity swite  |  | s) + sensitivity switch    | time (max.4ms)          | 1.5ms+6ms max.<br>(sampling average: ) |  |
| Despages            | Time     | Standard Mode                         | max.12.5ms: san  | 13ms+6ms max.<br>(sampling average: 16                       |                            |                         |  |  |
| Response            | rune     | High-resolution<br>Mode               | max.36.5ms: samp   | 49ms+6ms max.<br>(sampling average: 64                       |                            |                         |  |  |
|                     |          | Sensitivity Switch<br>Time            | 4ms max.   |  |                            |                         |  |  |
|                     | Indic    | ator                                  | Distance indicator: 7 bar LED display; output indicator: ON state: orange Q1/Q2 indicator (orange) light |  |                            |                         |  |  |
|                     | IP Ra    | ting                                  | IP67   |  |                            |                         |  |  |
| Operat              | ting Ter | np./Humidity                          | -10~45° C/35~85%RH(no condensation or icing)   |  |                            |                         |  |  |
| Storag              | e Temp   | o./Humidity                           | -20~60° C/35~95%RH(no condensation or icing)   |  |                            |                         |  |  |
| Ambient Illuminance |          | Sunlight: ≤ 10000lux, lamp: ≤ 3000lux |  |  |                            |                         |  |  |
| Vibr                | ation R  | esistance                             | 10~55  | Hz, double amplitude 1.5mm,X、Y、Z directions, 2 hour for each |                            |                         | for each                               |  |
| Sh                  | ock Re   | sistance                              |  |  | 50G (500m/s <sup>2</sup> ) |                         |  |  |
| He                  | ousing   | Material                              | Housing: PBT Lens: PMMA  |  |                            |                         |  |  |
| Weight              |          | Cable type: 65g : Plug-in type: 70g   |  |  |                            |                         |  |  |

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#### Output

| 分类                      | 2CH (Switching Output) | 2CH+Analog Current Output  | 2CH+Analog Voltage Output | 1CH+RS422                |  |  |  |
|-------------------------|------------------------|--|---------------------------|--------------------------|--|--|--|
| Power Supply<br>Voltage | 12-24V DC              | (-5%,+10%)   | 18-24V DC<br>(-5%, +10%)  | 12-24V DC<br>(-5%, +10%) |  |  |  |
| Current<br>Consumption  | max.55mA(24VDC)        | max.85mA(24VDC)  | max.55mAl                 | (24VDC)                  |  |  |  |
| Switching Q1<br>Output  | NPN or PNP open        | NPN or PNP open collector, $\leqslant$ 100mA/30V DC, residual voltage $\leqslant$ 1.8V |                           |                          |  |  |  |
| Switching Q2<br>Output  | NPN or PNP open        | NPN or PNP open collector, $\leqslant$ 100mA/30V DC, residual voltage $\leqslant$ 1.8V |                           |                          |  |  |  |
| Analog Output           | 1                      | 4-20mA   | 0-10V                     | 1                        |  |  |  |
| Communication           |                        | RS422  |                           |                          |  |  |  |
| Cable Type              | Ф5mm 5-pin 2m cable    | Ф5mm 6-р   | Ф5mm 8-pin 2m cable       |                          |  |  |  |
| Plug-in Type            | M12 8-pin              |  |                           |                          |  |  |  |

#### Retro-reflective

|                          | 2CH+Analog Current      | KD50-L30N(P)I   | KD50-L50N(P)1                      | KD50-L85N(P)I             |  |  |
|--------------------------|-------------------------|---|------------------------------------|---------------------------|--|--|
| Cable Type               | 2CH+Analog Voltage      | KD50-L30N(P)U   | KD50-L50N(P)U                      | KD50-L85N(P)U             |  |  |
|                          | 1CH+RS422               | KD50-L30N(P)/R2   | KD50-L50N(P)/R2                    | KD50-L85N(P)/R2           |  |  |
|                          | 2CH+Analog Current      | KD50-L30N(P)I-A8  | KD50-L50N(P)I-A8                   | KD50-L85N(P)I-A8          |  |  |
| Plug-in Type             | 2CH+Analog Voltage      | KD50-L30N(P)U-A8  | KD50-L50N(P)U-A8                   | KD50-L85N(P)U-A8          |  |  |
| Out                      | ICH+K5422               | KD50-L30N(P)/R2-A8  | KU50-L50N(P)/RZ-A8                 | KD50-L85N(P)/R2-A8        |  |  |
| 000                      | put signat              | Switching output: NPN (-N), PNP (-P)  |                                    |                           |  |  |
| Dete                     | ction Range             | 26.3±2mm  | 47.3±5mm                           | 82.9±10mm                 |  |  |
| Full                     | Scale (F.S.)            | 4mm   | 10mm                               | 20mm                      |  |  |
| Lig                      | ht Source               | Red   | Red Laser diode (wavelength 655nm) |                           |  |  |
| 1                        | 收光功率                    |   | 390µW max.                         |                           |  |  |
| IEC,                     | JIS Rating              |   | Class 1                            |                           |  |  |
| FC                       | 0A Rating               |   | Class II                           |                           |  |  |
| Samp                     | oling Period            | 500 (250mm: 750) /1000  | 0/1500/2000μs; factory setting     | ;: 500μs (250mm: 750μs)   |  |  |
|                          | Near Range              | 0.15 x 0.15mm   |                                    |                           |  |  |
| Spot Size                | Center Range            | 0.1x 0.1mm  |                                    |                           |  |  |
|                          | Far Range               | 0.15 x 0.15 mm  |                                    |                           |  |  |
| Linea                    | Linearity Accuracy      |   | ±0.2%F.S.                          |                           |  |  |
| Rep                      | peatability             | Iµm   | 2.5µm                              | 5µm                       |  |  |
| Temp                     | erature Drift           | ±0.08%F.S./*C   |                                    |                           |  |  |
|                          | High-speed Mode         | max.5ms: sampling average x 1 (1ms) + sensitivity switch time (max.4ms)     |                                    |                           |  |  |
| Development Time         | Standard Mode           | max.12.5ms: sampling average x 16 (8.5ms) + sensitivity switch time (max.4m |                                    | ity switch time (max.4ms) |  |  |
| Response time            | High-resolution Mode    | max.36.5ms: sampling average x 64 (32.5ms) + sensitivity switch time (max   |                                    | ity switch time (max.4ms) |  |  |
|                          | Sensitivity Switch time | 4ms max.  |                                    |                           |  |  |
| In                       | ndicator                |   |                                    |                           |  |  |
| li                       | P Rating                | IP67  |                                    |                           |  |  |
| Operating Temp./Humidity |                         | -10~45° C/35~85%RH (no condensation or icing)                               |                                    |                           |  |  |
| Storage Temp./Humidity   |                         | -20~60° C/35~95%RH (no condensation or icing)                               |                                    |                           |  |  |
| Ambient Illuminance      |                         | Lamp: ≤ 3000lux   |                                    |                           |  |  |
| Vibration Resistance     |                         | 10~55Hz, double amplitude 1.5mm,X、Y、Z directions, 2 hour for each           |                                    |                           |  |  |
| Shock Resistance         |                         | 50G (500m/s <sup>2</sup> ) X、Y、Z 3 times for each                           |                                    |                           |  |  |
| Housing Material         |                         | Housing: PBT Lens: PMMA   |                                    |                           |  |  |
| Weight                   |                         | Cable type: 65g : Plug-in type: 70g   |                                    |                           |  |  |

#### **Circuit Diagram**

#### NPN (Switching/Analog Output)



#### PNP (Switching/Analog Output)

|     | 司法   | ×<br>× | BN                                     | + 12-24V DC (2CH/analog current output)<br>18-24V DC (analog voltage output) |
|-----|------|--------|--|--|
|     | Ŧ    | BK     | <ul> <li>Switching Output 1</li> </ul> |  |
| ain |      |        | VT                                     | <ul> <li>Switching Output 2</li> </ul>                                       |
| lă  | - 10 | K GR   | GR                                     | MF remote input  |
|     | 7    | -      | BO                                     | 0V DC  |
| ЦĘ  | 学家   |        | 1                                      | <ul> <li>Analog Grouding</li> </ul>  |
|     |      |        | *Analog output                         |  |

#### NPN (RS422 communication)

|   | ± KI BN | + 12-24V DC                            |
|---|---------|--|
| 云来                                      |         | <ul> <li>Switching Output 2</li> </ul> |
| S Protection                            | DH GR   | <ul> <li>MF remote input</li> </ul>    |
| 2                                       | OE      | • RXD+                                 |
| 13                                      | PN      | • RXD-                                 |
| 5                                       | BK      | TXD+                                   |
| 100 10 10 10 10 10 10 10 10 10 10 10 10 | WH      | • TVD                                  |
| └──                                     | BU      | - 0V DC                                |

#### PNP (RS422 communication)

| -   |               | BN | + 12-24V DC        |
|-----|---------------|----|--------------------|
|     | Prosectice 来来 | VT |                    |
| ×   |               | OE | Switching Output 2 |
| ain | 1             | BK | • TXD+             |
| 0   |               | BK | PXD+               |
| 5   |               | WH | • RXD-             |
| æ.  | 老老老孝          | GR | - NAD.             |
| -   |               | BU | MF remote input:   |

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#### **Applications:**

KRONZ Photoelectric Sensors are versatile devices suitable for a wide range of applications across various industries. With a compact – design and high precision technology, these sensors offer reliable performance in different scenarios. CMOS laser mounted photoelectric sensors for the electronics/semiconductor industry

PCB Component Height Inspection : Measures the height of chips, capacitors, and other components on printed circuit boards to ensure proper placement.

Die Bonding and Chip Alignment: Ensures precision alignment of chips during packaging and bonding processes.

Wafer Thickness and Warpage Detection: Used in wafer polishing or cutting processes to control material removal and prevent damage.

FPC (Flexible PCB) Thickness Measurement: Ensures uniform lamination and layer thickness in flexible circuit boards.

## **ABOUT US**

KRONZ is a manufacturing enterprise located in Zengcheng District, Guangzhou City. We focus on providing customers with high-efficiency industrial automation solutions and related industrial products. After many years of innovation and development, KRONZ has complete product processing equipment and a professional team who are proficient in various automation technologies.

In order to improve the quality of products and production efficiency, we continue to introduce advanced production equipment and technology, strengthen investment in research and development. At present, our main products include Industrial Connectors. Inductive Sensors. Capacitive Sensors. Photoelectric Sensors. Ultrasonic Sensors. Industrial power supplies. Industrial fieldbus. RFID recognition systems. Industrial Ethernet Switches

We not only produce the orders of standard products, but also have ability to make customize production based on customer design drawings or samples.

Adhering to the principle of mutual benefit, we provide our customers with competitive prices , and perfect after-sales service. Kronz's products have been sold in multiple countries, have won the trust and praise of customers. KRONZ expect to collaborate with you.





# **Logistics and Payment**











1. Samples and small orders can be shipped with fast shippment method, by air and by express. Bulk order will ship by sea,by air,by train,by truck etc.

2.We also can send the goods to your agent warehouse.

3. If you need any more shipping method, please feel free to contact with us.

